

# 2PD602AQL; 2PD602ARL; 2PD602ASL

50 V, 500 mA NPN general-purpose transistors

Rev. 01 — 27 October 2008

**Product data sheet** 

## 1. Product profile

## 1.1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number[1]	Package	PNP complement	
	NXP	JEDEC	
2PD602AQL	SOT23	TO-236AB	-
2PD602ARL			2PB710ARL
2PD602ASL			2PB710ASL
2PD602AQL/DG	SOT23	TO-236AB	-
2PD602ARL/DG			2PB710ARL/DG
2PD602ASL/DG			2PB710ASL/DG

<sup>[1] /</sup>DG: halogen-free

#### 1.2 Features

- General-purpose transistors
- Three current gain selections
- AEC-Q101 qualified
- Small SMD plastic package

## 1.3 Applications

■ General-purpose switching and amplification

## 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
I <sub>C</sub>	collector current		-	-	500	mΑ



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Table 2. Quick reference data ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h <sub>FE</sub>	DC current gain	$V_{CE} = 10 \text{ V};$ $I_{C} = 150 \text{ mA}$	<u>[1]</u>			
	h <sub>FE</sub> group Q		85	-	170	
	h <sub>FE</sub> group R		120	-	240	
	h <sub>FE</sub> group S		170	-	340	

<sup>[1]</sup> Pulse test:  $t_p \le 300 \,\mu\text{s}$ ;  $\delta \le 0.02$ .

# 2. Pinning information

Table 3. Pinning

	9		
Pin	Description	Simplified outline	Graphic symbol
1	base	—	_
2	emitter	<u> </u>	3
3	collector	1 2	1 —
			sym021

# 3. Ordering information

Table 4. Ordering information

Type number[1]	Package				
	Name	Description	Version		
2PD602AQL	· <b>-</b>	plastic surface-mounted package; 3 leads	SOT23		
2PD602ARL					
2PD602ASL					
2PD602AQL/DG	-	plastic surface-mounted package; 3 leads	SOT23		
2PD602ARL/DG					
2PD602ASL/DG					

<sup>[1] /</sup>DG: halogen-free

# 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
2PD602AQL	SH*
2PD602ARL	SG*
2PD602ASL	SF*

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Table 5. Marking codes ...continued

Type number	Marking code <sup>[1]</sup>
2PD602AQL/DG	SX*
2PD602ARL/DG	SW*
2PD602ASL/DG	SV*

<sup>[1] \* = -:</sup> made in Hong Kong

## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{CBO}}$	collector-base voltage	open emitter	-	60	V
$V_{\text{CEO}}$	collector-emitter voltage	open base	-	50	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	500	mA
$I_{CM}$	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	1	Α
I <sub>BM</sub>	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> -	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		<b>–</b> 55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

## 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	500	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

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## 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$	-	-	10	nΑ
		$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 4 \text{ V}; I_{C} = 0 \text{ A}$	-	-	10	nΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = 10 \text{ V};$ $I_{C} = 500 \text{ mA}$	[1] 40	-	-	
	h <sub>FE</sub> group Q	$V_{CE} = 10 \text{ V};$ $I_{C} = 150 \text{ mA}$	[1] 85	-	170	
	h <sub>FE</sub> group R	$V_{CE} = 10 \text{ V};$ $I_{C} = 150 \text{ mA}$	120	-	240	
	h <sub>FE</sub> group S	$V_{CE} = 10 \text{ V};$ $I_{C} = 150 \text{ mA}$	<u>[1]</u> 170	-	340	
$V_{\text{CEsat}}$	collector-emitter saturation voltage	$I_C = 300 \text{ mA};$ $I_B = 30 \text{ mA}$	[1] -	-	600	mV
f <sub>T</sub>	transition frequency	$V_{CE} = 10 \text{ V};$ $I_{C} = 50 \text{ mA};$ f = 100  MHz	<u>[1]</u>			
	h <sub>FE</sub> group Q		140	-	-	MHz
	h <sub>FE</sub> group R		160	-	-	MHz
	h <sub>FE</sub> group S		180	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ f = 1  MHz	-	-	15	pF

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

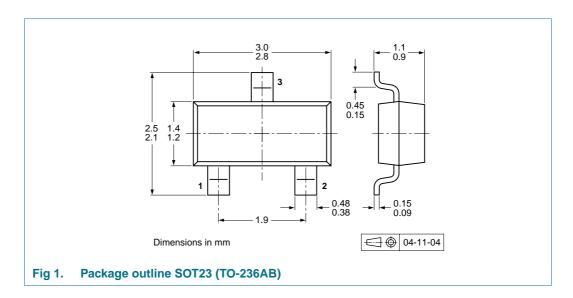
## 8. Test information

## 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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## 9. Package outline



# 10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

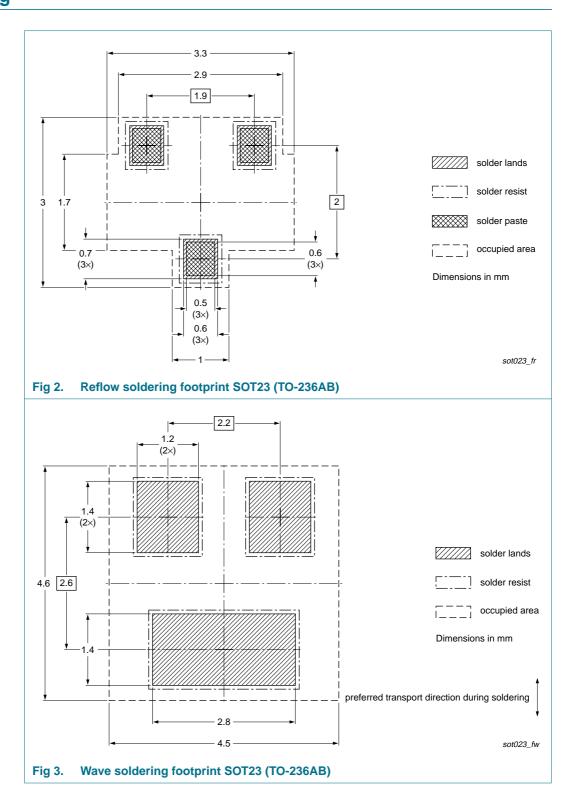
Type number[2]	Package	Description	Packing quantity		
			3000	10000	
2PD602AQL	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	
2PD602ARL					
2PD602ASL					
2PD602AQL/DG	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	
2PD602ARL/DG					
2PD602ASL/DG					

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

<sup>[2] /</sup>DG: halogen-free

## 50 V, 500 mA NPN general-purpose transistors

## 11. Soldering



## 50 V, 500 mA NPN general-purpose transistors

# 12. Revision history

## Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
2PD602AXL_1	20081027	Product data sheet	-	-

#### 50 V, 500 mA NPN general-purpose transistors

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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# 2PD602AxL

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